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## **Dual Common Cathode Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance



| PRIMARY CHARACTERISTICS |                        |  |  |  |  |  |  |
|-------------------------|------------------------|--|--|--|--|--|--|
| I <sub>F(AV)</sub>      | 30 A                   |  |  |  |  |  |  |
| V <sub>RRM</sub>        | 35 V, 45 V, 50 V, 60 V |  |  |  |  |  |  |
| I <sub>FSM</sub>        | 200 A                  |  |  |  |  |  |  |
| V <sub>F</sub>          | 0.58 V, 0.63 V         |  |  |  |  |  |  |
| I <sub>R</sub>          | 150 μΑ                 |  |  |  |  |  |  |
| T <sub>J</sub> max.     | 175 °C                 |  |  |  |  |  |  |
| Package                 | TO-3P (TO-247AD)       |  |  |  |  |  |  |
| Circuit configuration   | Common cathode         |  |  |  |  |  |  |

#### **FEATURES**

- Power pack
- · Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- · Low leakage current
- · High forward surge capability
- High frequency operation
- Solder dip 275 °C max.10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-3P (TO-247AD)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)                                 |                                 |                |            |            |            |      |  |  |
|---|---------------------------------|----------------|------------|------------|------------|------|--|--|
| PARAMETER   | SYMBOL                          | MBR30H35PT     | MBR30H45PT | MBR30H50PT | MBR30H60PT | UNIT |  |  |
| Maximum repetitive peak reverse voltage   | $V_{RRM}$                       | 35             | 45         | 50         | 60         | V    |  |  |
| Maximum working peak reverse voltage  | $V_{RWM}$                       | 35             | 45         | 50         | 60         | V    |  |  |
| Maximum DC blocking voltage   | $V_{DC}$                        | 35             | 45         | 50         | 60         | V    |  |  |
| Maximum average forward rectified current (fig. 1)  | I <sub>F(AV)</sub>              | 30             |            |            |            |      |  |  |
| Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 1.5 \text{ A}, L = 10 \text{ mH}$ | E <sub>AS</sub>                 | 80             |            |            |            |      |  |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode    | I <sub>FSM</sub>                | 200            |            |            |            |      |  |  |
| Peak repetitive reverse surge current per diode   | I <sub>RRM</sub> <sup>(1)</sup> | 2.0 1.0        |            |            |            | Α    |  |  |
| Peak non-repetitive reverse energy (8/20 µs waveform)   | E <sub>RSM</sub>                | 30 20          |            |            | mJ         |      |  |  |
| Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 $\Omega$        | V <sub>C</sub>                  | 25             |            |            |            |      |  |  |
| Voltage rate of change (rated V <sub>R</sub> )  | dV/dt                           | 10 000         |            |            |            |      |  |  |
| Operating junction temperature range  | TJ                              | -65 to +175    |            |            |            |      |  |  |
| Storage temperature range   | T <sub>STG</sub>                | -65 to +175 °C |            |            |            |      |  |  |

#### Note

 $^{(1)}$  2.0 µs pulse width, f = 1.0 kHz



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                               |                      |                         |                          |      |                          |      |      |  |
|---|-------------------------------|----------------------|-------------------------|--------------------------|------|--------------------------|------|------|--|
| PARAMETER   | SYMBOL                        | TEST CONDITIONS      |                         | MBR30H35PT<br>MBR30H45PT |      | MBR30H50PT<br>MBR30H60PT |      | UNIT |  |
|   |                               |                      |                         | TYP.                     | MAX. | TYP.                     | MAX. |      |  |
| Maximum instantaneous forward voltage per diode                                   | V <sub>F</sub> <sup>(1)</sup> | $I_F = 20 A$         | T <sub>J</sub> = 25 °C  | -                        | 0.66 | -                        | 0.74 | V    |  |
|   |                               | $I_F = 20 \text{ A}$ | T <sub>J</sub> = 125 °C | 0.54                     | 0.58 | 0.60                     | 0.63 |      |  |
|   | v <sub>F</sub> ···            | $I_F = 30 \text{ A}$ | $T_J = 25  ^{\circ}C$   | ı                        | 0.73 | -                        | 0.83 | ]    |  |
|   |                               | $I_F = 30 A$         | T <sub>J</sub> = 125 °C | 0.62                     | 0.66 | 0.66                     | 0.70 |      |  |
| Maximum reverse current at rated $V_{\text{R}}$ per diode                         | I <sub>R</sub> <sup>(2)</sup> |                      | $T_J = 25  ^{\circ}C$   | ı                        | 150  | -                        | 150  | μA   |  |
|   | 'R`'                          |                      | T <sub>J</sub> = 125 °C | 6.0                      | 25   | 4.0                      | 25   | mA   |  |

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

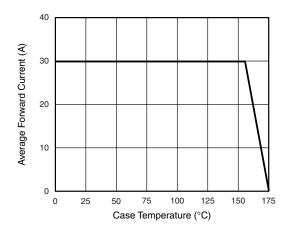
| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                |   |  |  |  |      |  |  |
|---|----------------|---|--|--|--|------|--|--|
| PARAMETER   | SYMBOL         | MBR30H35PT MBR30H45PT MBR30H50PT MBR30H60PT |  |  |  |      |  |  |
| Thermal resistance, junction to case per diode                          | $R_{	heta JC}$ | 1.4   |  |  |  | °C/W |  |  |

| ORDERING INFORMATION (Example) |                  |                 |              |               |               |  |  |  |
|--------------------------------|------------------|-----------------|--------------|---------------|---------------|--|--|--|
| PACKAGE                        | PREFERRED P/N    | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |  |
| TO-247AD                       | MBR30H45PT-E3/45 | 6.13            | 45           | 30/tube       | Tube          |  |  |  |



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### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)



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Fig. 1 - Forward Current Derating Curve

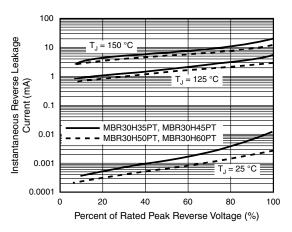


Fig. 4 - Typical Reverse Characteristics Per Diode

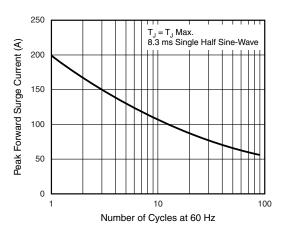


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

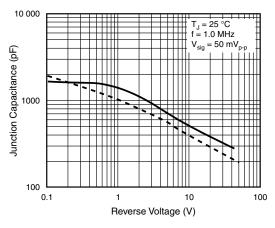


Fig. 5 - Typical Junction Capacitance Per Diode

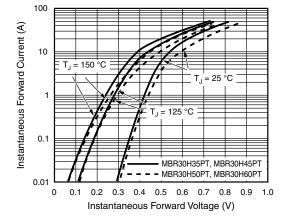


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

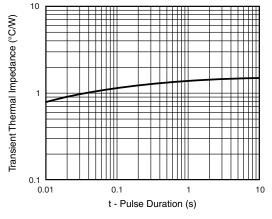


Fig. 6 - Typical Transient Thermal Impedance Per Diode

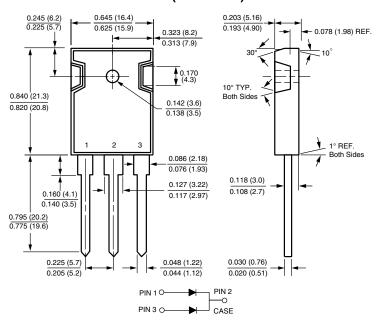


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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### TO-3P (TO-247AD)





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